NSN 5961-00-479-1544

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Inclosure Material:
Metal
Overall Length:
1.453 inches
Overall Diameter:
0.667 inches
Function For Which Designed:
Zener diode
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-5
Electrode Internally-electrically Connected To Case:
Cathode
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
Between 0.667 inches and 0.687 inches
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 regulator voltage
Voltage Tolerance In Percent:
-5.0/+5.0
Current Rating Per Characteristic:
480.00 milliamperes source cutoff current horsepower metric
Power Rating Per Characteristic:
50.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius case
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Designator:
Unf
Terminal Type And Quantity:

Specification Data: 81349-mil-s-19500/358 government specification

1 threaded stud and 1 tab, solder lug

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N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0